

ZnO(In) SCINTILLATION LIGHT SPECTRA INVESTIGATION FOR HEAVY ION DETECTOR APPLICATION^{*†}

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Abstract

ZnO-based ceramics are known as promising scintillators exhibiting light emission in the ultraviolet (UV) spectral region (~390 nm) and ultrafast decay times (<1 ns). They are of great interest for applications in scintillation counters and screens at high-energy heavy ion accelerators. In this contribution, the deterioration of scintillating properties of ZnO-based ceramics subjected to heavy ion exposure at high doses is investigated. The scintillation light spectra of ZnO(In) as a function of fluence for 4.8 MeV/u ⁴⁸Ca and ¹⁹⁷Au ions were studied. We observed that the deterioration of the scintillation intensity with increasing fluence follows the Birks-Black model.

INTRODUCTION

Zinc oxide is a multi-functional material with many applications due to its interesting properties [1, 2]. In particular, since the 1960s it has been known as a promising scintillation material that exhibits sub-nanosecond fast light emission at room temperature [3–5]. Previously, pure and doped ZnO has been produced in various forms (powder, thin films, single- and poly-crystals, and ceramics) with the purpose of detecting different types of ionizing radiation [6–9].

Recent studies and technological advances have made it possible to produce bulk pieces of indium- and gallium-doped zinc oxide ceramics (ZnO(In) and ZnO(Ga)) by uniaxial hot pressing in vacuum [10, 11]. These scintillating ceramics become highly interesting for heavy-ion radiation detection at accelerator facilities like GSI and the future FAIR facility in Darmstadt, Germany [12]. ZnO(In) and ZnO(Ga) scintillators are considered as promising candidates to substitute plastic scintillator BC400 commonly used for beam intensity monitoring and spill micro-structure characterization at SIS-18 synchrotron, where ion beams from proton to uranium with energies from 150 MeV/u to 4.5 GeV/u can be obtained.

As a part of a research and development project for a radiation-resistant fast scintillation detector, we report on the performance and in-situ characterization of ZnO(In) ceramics scintillation light spectra change as a function of ion fluence.

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ZnO(In) SCINTILLATION SPECTRA

The investigated ZnO(In) ceramic samples were produced in the form of 8 mm × 8 mm × 0.4 mm size plates at the Joint Stock Company “Research and Production Corporation S.I. Vavilova” (St. Petersburg, Russia). The samples were produced with 0.046 at % In³⁺ doping concentration. Samples density estimated from mass and volume measurements was 4.66 g/cm².

In-situ characterization of scintillation light spectra was performed using 4.8 MeV/u energy ⁴⁸Ca and ¹⁹⁷Au ions from UNiversal Linear ACcelerator (UNILAC) of the GSI Helmholtz Center for Heavy Ion Research GmbH (Darmstadt, Germany) [13]. The irradiations were carried out at room temperature in vacuum at a beam incidence angle of 45° with respect to the sample surface.

Scintillation light was collected with a lens placed in front of the ion-incident surface of the sample. The collected light was transferred via a light guide to an Ocean Optics QE-Pro spectrometer. The acquired spectra were corrected for dark counts and normalized by the number of ions that hit the sample during the spectrum acquisition.

Figure 1 shows how the scintillation light spectrum of ZnO(In) ceramic sample changes as a result of 4.8 MeV/u ⁴⁸Ca ion irradiation. The spectra have only one emission

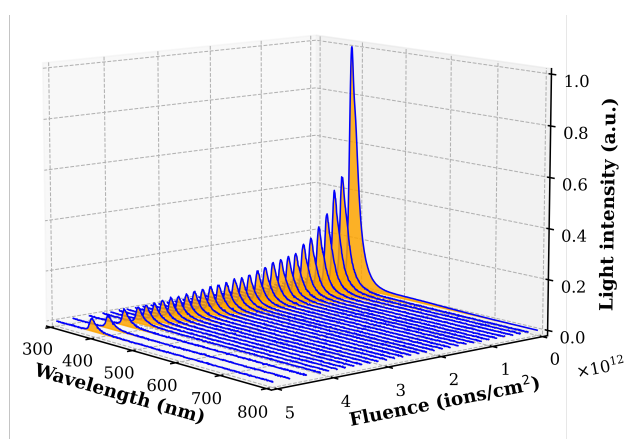


Figure 1: Spectra of ZnO(In) ceramic as a function of 4.8 MeV/u ⁴⁸Ca ion fluence.

band in the ultraviolet (UV) light region with a maximum at around 387 nm. The observed peak corresponds to the near-band-edge emission (NBE) known for scintillation decay times less than nanosecond. With increasing fluence, the

intensity of this NBE band drops considerably. No new light emission bands are formed as a result of the ion irradiation, not even at the highest fluences reached, 5×10^{12} Ca-ions/cm² and 2×10^{11} Au-ions/cm².

BIRKS-BLACK MODEL FIT

The Birks-Black model [14] was used to fit the observed NBE peak intensity reduction as a function of Ca and Au ion fluence. According to this model, the reduction of the scintillation light intensity can be presented as:

$$\frac{I(\Phi)}{I_0} = \frac{1}{1 + \frac{\Phi}{\Phi_{1/2}}}, \quad (1)$$

where I_0 is the initial scintillation light intensity, and $\Phi_{1/2}$ is the critical fluence at which the scintillation light intensity is reduced by 50% of the initial value.

Figure 2 shows the NBE peak intensity as a function of the Ca and Au ion fluence. The intensity evolution follows the Birks-Black model for both ion species. The critical fluence values extracted from a fit of Eq. (1) to the data are 3.3×10^{11} Ca-ions/cm² and 3.5×10^9 Au-ions/cm², respectively.

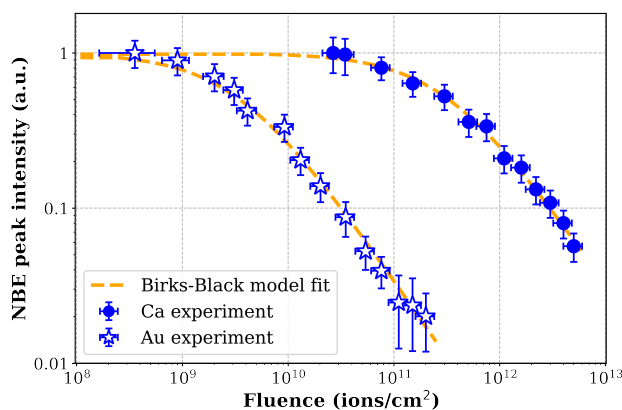


Figure 2: Intensity of the NBE peak (387 nm) of the scintillation spectrum as a function of irradiation fluence using ⁴⁸Ca ions (full circles) and ¹⁹⁷Au ions (open stars). The dashed line represent fits with Eq. (1) from the Birks-Black model.

CONCLUSIONS

ZnO-based scintillating ceramics are promising materials to be used for heavy-ion particle detection applications. In this work, ZnO(In) scintillating ceramics were exposed to 4.8 MeV/u ⁴⁸Ca and ¹⁹⁷Au ion beams in order to investigate the changes in scintillation light spectrum as a function of swift heavy ion fluence. The scintillation light intensity follows the trend predicted by the Birks-Black model. As a result of high fluence irradiation, no new peak formation was

observed up to 5×10^{12} Ca-ions/cm² and 2×10^{11} Au-ions/cm² irradiation at 4.8 MeV/u energy.

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